

Features

- 1.2kV Schottky Rectifier
- Zero Reverse Recovery Current
- High-Frequency Operation
- Temperature-Independent Switching
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies (SMPS)
- Boost diodes in PFC or DC/DC stages
- Free Wheeling Diodes in Inverter stages
- AC/DC converters



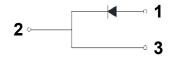


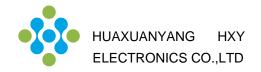
Part Number	Package	Qty(PCS)	
HFFSP15120A	TO-220C-2L	50	

Maximum Ratings (T_c=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	Test Conditions	Notes	
Repetitive Peak Reverse Voltage	V_{RRM}	1200				
DC Blocking Voltage	V_{DC}	1200	V			
		43.5		T _J = 25 °C		
Continuous Forward Current	I _F	21		T _J = 135 °C	Fig. 3	
		15		T _J = 152.5 °C		
Repetitive Peak		68		T _C = 25 °C, t _p = 10 ms, Half Sine Wave		
Forward Surge Current	FRM	44	Α	T _C = 110 °C, t _p = 10 ms, Half Sine Wave		
Non-Repetitive Forward	I _{FSM}	100		T _C = 25 °C, t _p = 10 ms, Half Sine Wave	Fig. 8	
Surge Current		85		T _C = 110 °C,t _p = 10 ms, Half Sine Wave		
Non-Repetitive Peak		900		$T_{\rm C}$ = 25 °C, $t_{\rm p}$ = 10 μ s, Pulse		
Forward Surge Current	I _{F,Max}	750		$T_{\rm C}$ = 110°C, $t_{\rm p}$ = 10 µs, Pulse		
B	P _{tot}	214	W	T _J = 25 °C	Fig. 4	
Power Dissipation		93		T _J = 110 °C		
10. 1 4	ʃi²t	50	A²s	$T_{\rm C}$ = 25 °C, $t_{\rm p}$ = 10 ms		
i²t Value		36		$T_{c} = 110^{\circ}C, t_{p} = 10 \text{ ms}$		







Electrical Characteristics

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions	Notes
- 177.6		1.6	1.8		I _F = 15 A, T _i = 25 °C	,
Forward Voltage	V _F	2.2	3	V	I _F = 15 A, T _i = 175 °C	Fig. 1
		35	200		V _R = 1200 V, T _i = 25 °C	F: 0
Reverse Current	l _R	120	300	μA	V _R = 1200 V, T _i = 175 °C	Fig. 2
Total Capacitive Charge	Q_{c}	77.5		nC	V _R = 800 V, T _i = 25 °C	Fig. 5
		1200			$V_R = 0 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	
Total Capacitance	С	70		pF	$V_R = 400 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	Fig. 6
		50			V _R = 800 V, T _j = 25 °C, f = 1 MHz	
Capacitance Stored Energy	E _c	22		μJ	V _R = 800 V	Fig. 7

Notes:

SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

Thermal & Mechanical Characteristics

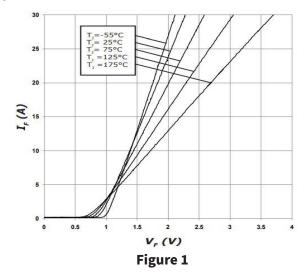
Parameter	Symbol	Value	Unit	Notes
Thermal Resistance, Junction to Case (Typical)	R _{e, JC (TYP)}	0.7	°C/W	
Junction Temperature	T _j	-55 to +175	°C	
Case & Storage Temperature	T _c	-55 to +175		
		1	Nm	M3 Screw
TO-220-2L Mounfting Torque	-	8.8	lbf-in	6-32 Screw

Electrostatic Discharge (ESD) Classifications

Parameter		Notes
Human Body Model	НВМ	Class 3B (≥ 8000 V)
Charge Device Model	CDM	Class C3 (≥ 1000 V)



Typical Performance



Forward Characteristics

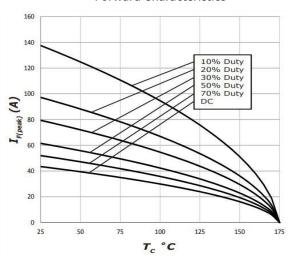
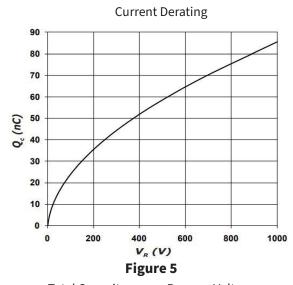


Figure 3



Total Capacitance vs. Reverse Voltage

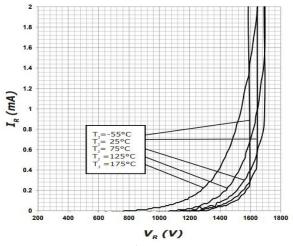


Figure 2

Reverse Characteristics

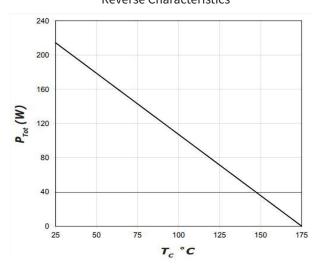
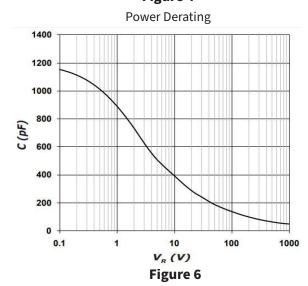


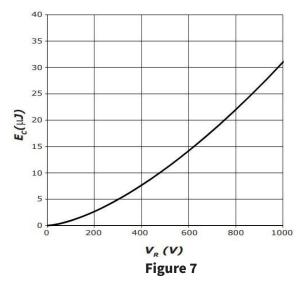
Figure 4



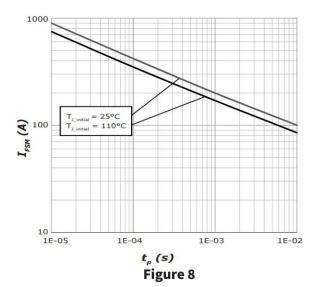
Capacitace vs. Reverse Voltage



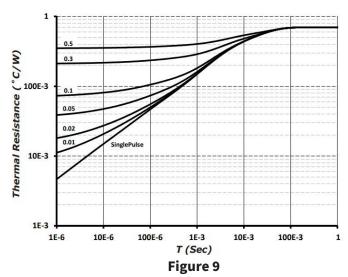
Typical Performance



Capacitance Stored Energy



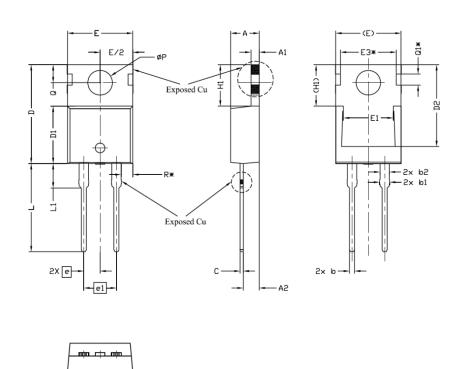
Non-Repetitive Peak Forward Surge Current versus Pulse Duration (sinusoidal waveform)



Transient Thermal Impedance

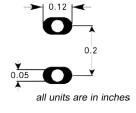


Package Information TO-220C-2L



6) // ID 61				
SYMBOL	MIN.	NOM.	MAX.	NOTES
Α	4,24	4,44	4,64	
A1	1.15	1.27	1.40	
A2	2.30	2.48	2.70	
ь	0.70	0.80	0.90	
b1	1.20	1.55	1.75	
b2	1.20	1.45	1.70	
С	0.40	0.50	0.60	
D	14.70	15.37	16.00	4
D1	8.82	8.92	9.02	
D2	12.43	12.73	12.83	5
E	9.96	10.16	10.36	4,5
E1	6,86	7,77	8.89	5
E3*		8.70REF.		
e	2,54BSC			
e1	5.08BSC			
H1	6.30	6.45	6.60	5,6
L	13,47	13.72	13.97	
L1	3.60	3.80	4.00	
ØP	3,75	3.84	3.93	
Q	2,60	2,80	3,00	
Q1*	1.73REF.			
R*				

Recommended Solder Pad Layout



TO-220C-2L



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